

STTH1302CT/CG/CFP

HIGH EFFICIENCY ULTRAFAST DIODE

MAIN PRODUCT CHARACTERISTICS

I _{F(AV)}	2 x 6.5 A
V _{RRM}	200 V
Tj (max)	175 °C
V _F (max)	0.95 V
trr (max)	25 ns

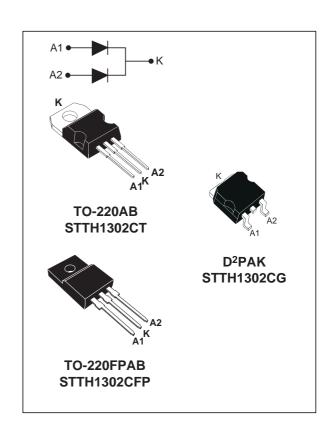
FEATURES AND BENEFITS

- Suited for SMPS
- Low losses
- Low forward and reverse recovery times
- High surge current capability
- High junction temperature
- Insulated package: TO-220FPAB: Insulation voltage = 2000 V_{DC} Capacitance = 12 pF

DESCRIPTION

Dual center tap rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters.

This device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values, per diode)

Symbol		Value	Unit			
V_{RRM}	Repetitive peak reve	200	٧			
I _{F(RMS)}	RMS forward current	t			20	Α
I _{F(AV)}	Average forward	6.5	Α			
	current $\delta = 0.5$	D ² PAK	Tc = 145°C	Per device	13	
	TO-220FPAB Tc = 135°C Per diode				6.5	Α
		Tc = 110°C Per device				
I _{FSM}	Surge non repetitive	70	Α			
T _{stg}	Storage temperature range					ç
Tj	Maximum operating	junction temperatur	·e		175	ပ္စ

October 2003 - Ed: 2A 1/7

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THERMAL RESISTANCES

Symbol	Par	Value	Unit		
R _{th (j-c)}	Junction to case	TO-220AB / D ² PAK	3	°C/W	
		TO-220FPAB	TO-220FPAB		
		TO-220AB / D ² PAK Total		1.9	°C/W
		TO-220FPAB		4.5	
R _{th (c)}	Coupling	TO-220AB / D ² PAK		0.8	°C/W
		TO-220FPAB		3.5	

When the diodes 1 and 2 are used simultaneously:

 $\Delta \text{ Tj(diode 1)} = P(\text{diode1}) \times R_{\text{th(j-c)}}(\text{Per diode}) + P(\text{diode 2}) \times R_{\text{th(c)}}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests Conditions		Min.	Тур.	Max.	Unit
I _R *	Reverse leakage Current	Tj = 25°C	$V_R = V_{RRM}$			6	μΑ
		Tj = 125°C			3	60	
V _F **	Forward Voltage drop	Tj = 25°C	I _F = 6.5 A			1.1	V
		Tj = 125°C	$I_F = 6.5 A$		0.81	0.95	
		Tj = 25°C	I _F = 13 A			1.25	
		Tj = 125°C	I _F = 13 A		0.95	1.1	

Pulse test : $* tp = 5 ms, \delta < 2\%$

** $tp = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation :

 $P = 0.80 \text{ x } I_{F(AV)} + 0.023 \text{ x } I_{F}^{2}_{(RMS)}$

DYNAMIC CHARACTERISTICS (per diode)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
trr	Reverse recovery time	Tj = 25°C	$I_F = 0.5 A$ Irr = 0.25 A $I_R = 1 A$		16	25	ns
tfr	Forward recovery time	Tj = 25°C	$I_F = 6.5 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x V}_F \text{ max}$		70		ns
V _{FP}	Forward recovery voltage	Tj = 25°C	I _F = 6.5 A dI _F /dt = 100 A/μs		2.2		V

Fig. 1: Average forward power dissipation versus average forward current (per diode).

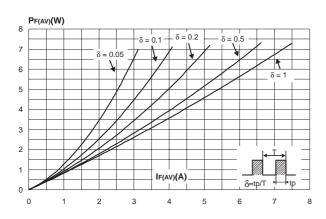


Fig. 3: Forward voltage drop versus forward current (per diode).

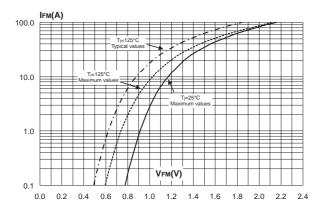


Fig. 4-2: Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB).

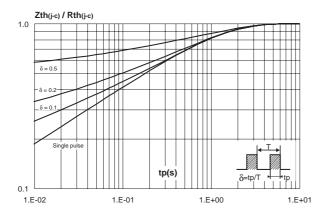


Fig. 2: Peak current versus factor (per diode).

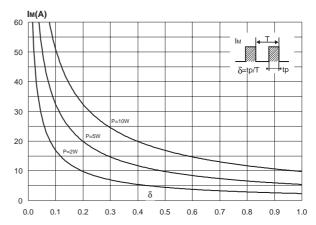


Fig. 4-1: Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB / D²PAK).

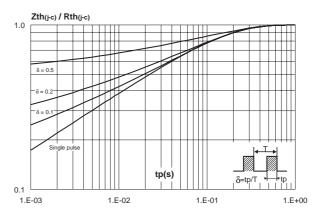
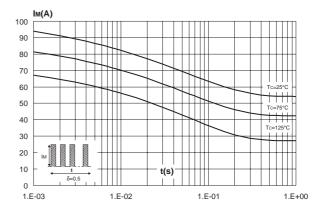


Fig. 5-1: Non repetitive surge peak forward current versus overload duration per diode (TO-220AB / D²PAK).



57

Fig. 5-2: Non repetitive surge peak forward current versus overload duration per diode (TO-220FPAB).

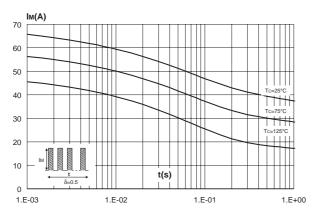


Fig. 7: Junction capacitance versus reverse voltage applied (typical values, per diode).

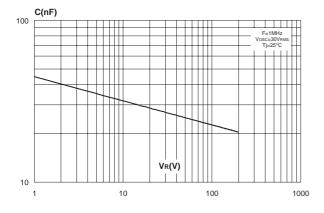


Fig. 9: Reverse recovery time versus dI_F/dt (90% confidence, per diode).

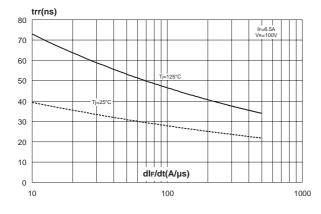


Fig. 6: Average forward current versus ambient temperature (δ =0.5, per diode).

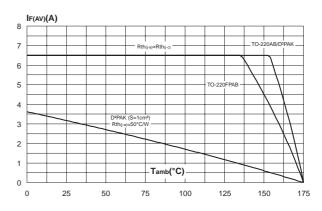


Fig. 8: Reverse recovery charges versus dI_F/dt (90% confidence, per diode).

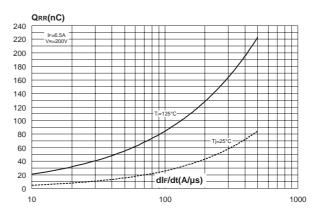
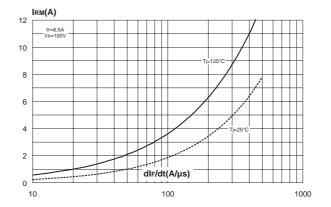


Fig. 10: Reverse recovery current versus dI_F/dt (90% confidence, per diode).



4/7

Fig. 11: Dynamic parameters versus junction temperature.

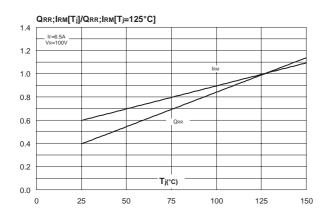
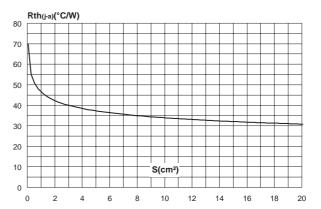
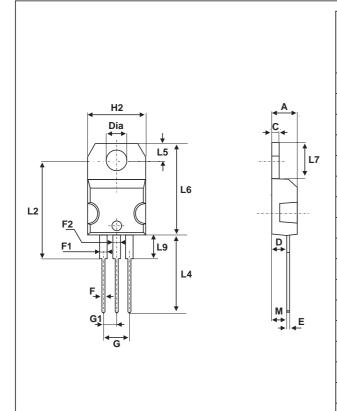


Fig. 12: Thermal resistance junction to ambient versus copper surface under tab (epoxy printed board FR4, $Cu = 35\mu m$)(D^2PAK).



PACKAGE MECHANICAL DATA

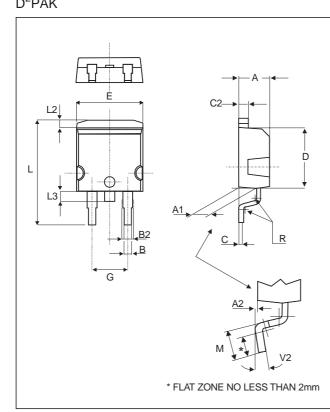
TO-220AB



REF.	DIMENSIONS						
	Millin	neters	Inc	hes			
	Min. Max.		Min.	Max.			
Α	4.40	4.60	0.173	0.181			
С	1.23	1.32	0.048	0.051			
D	2.40	2.72	0.094	0.107			
Е	0.49	0.70	0.019	0.027			
F	0.61	0.88	0.024	0.034			
F1	1.14	1.70	0.044	0.066			
F2	1.14	1.70	0.044	0.066			
G	4.95	5.15	0.194	0.202			
G1	2.40	2.70	0.094	0.106			
H2	10	10.40	0.393	0.409			
L2	16.4	typ.	0.645 typ.				
L4	13	14	0.511	0.551			
L5	2.65	2.95	0.104	0.116			
L6	15.25	15.75	0.600	0.620			
L7	6.20	6.60	0.244	0.259			
L9	3.50	3.93	0.137	0.154			
М	2.6	typ.	0.102	2 typ.			

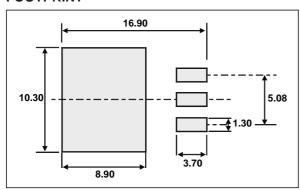
57

$\begin{array}{c} \textbf{PACKAGE MECHANICAL DATA} \\ \textbf{D}^2 \textbf{PAK} \end{array}$



REF.	DIMENSIONS						
	Millimeters		Inc	hes			
	Min.	Min. Max.		Max.			
А	4.40	4.60	0.173	0.181			
A1	2.49	2.69	0.098	0.106			
A2	0.03	0.23	0.001	0.009			
В	0.70	0.93	0.027	0.037			
B2	1.14	1.70	0.045	0.067			
С	0.45	0.60	0.017	0.024			
C2	1.23	1.36	0.048	0.054			
D	8.95	9.35	0.352	0.368			
E	10.00	10.40	0.393	0.409			
G	4.88	5.28	0.192	0.208			
L	15.00	15.85	0.590	0.624			
L2	1.27	1.40	0.050	0.055			
L3	1.40	1.75	0.055	0.069			
М	2.40	3.20	0.094	0.126			
R	0.40	typ.	0.010	6 typ.			

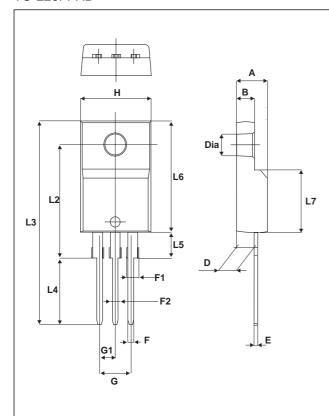
FOOTPRINT



6/7

PACKAGE MECHANICAL DATA

TO-220FPAB



REF.	DIMENSIONS						
	Millimeters		Inc	hes			
	Min.	Max.	Min.	Max.			
Α	4.4	4.6	0.173	0.181			
В	2.5	2.7	0.098	0.106			
D	2.5	2.75	0.098	0.108			
E	0.45	0.70	0.018	0.027			
F	0.75	1	0.030	0.039			
F1	1.15	1.70	0.045	0.067			
F2	1.15	1.70	0.045	0.067			
G	4.95	5.20	0.195	0.205			
G1	2.4	2.7	0.094	0.106			
Н	10	10.4	0.393	0.409			
L2	16	Тур.	0.63 Typ.				
L3	28.6	30.6	1.126	1.205			
L4	9.8	10.6	0.386	0.417			
L5	2.9	3.6	0.114	0.142			
L6	15.9	16.4	0.626	0.646			
L7	9.00	9.30	0.354	0.366			
Dia.	3.00	3.20	0.118	0.126			

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH1302CT	STTH1302CT	TO-220AB	2.20 g	50	Tube
STTH1302CFP	STTH1302CFP	TO-220FPAB	2.0 g	50	Tube
STTH1302CG	STTH1302CG	D ² PAK	1.48 g	50	Tube
STTH1302CG-TR	STTH1302CG	D ² PAK	1.48 g	1000	Tape & reel

■ Epoxy meets UL94,V0

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